# MSKSEMI















**ESD** 

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# Broduct data sheet

2SD882-MS HF 🚱





1. BASE

# TRANSISTOR (NPN)

2. COLLETOR

#### **FEATURES**

3. EMITTER

Power dissipation

#### MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	40	٧
V <sub>CEO</sub>	Collector-Emitter Voltage	30	٧
V <sub>EBO</sub>	Emitter-Base Voltage	6	٧
Ic	Collector Current -Continuous	3	Α
Pc	Collector Power Dissipation	0.5	W
TJ	Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55-150	$^{\circ}$

### **ELECTRICAL CHARACTERISTICS(Tamb=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 100μA, I <sub>E</sub> =0	40			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 10mA, I <sub>B</sub> =0	30			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 100μA, I <sub>C</sub> =0	6			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 40V, I <sub>E</sub> =0			1	μA
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> = 30V, I <sub>B</sub> =0			10	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 6V, I <sub>C</sub> =0			1	μA
DC current sein	h <sub>FE(1)</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> = 1A	60		400	
DC current gain	h <sub>FE(2)</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> = 100mA	32			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 2A, I <sub>B</sub> = 0.2 A			0.5	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> = 2A, I <sub>B</sub> = 0.2 A			1.5	٧
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 5V , Ic=0.1A f =10MHz	50			MHz

#### CLASSIFICATION OF $h_{\text{FE}(1)}$

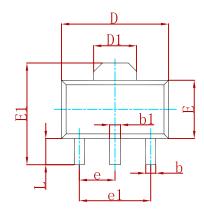
Rank	R	0	Y	GR
Range	60-120	100-200	160-320	200-400

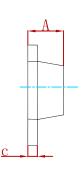
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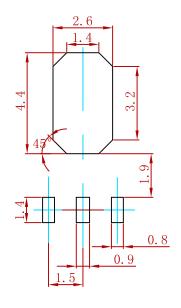
#### **PACKAGE MECHANICAL DATA**





Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.400	1.600	0.055	0.063	
b	0.320	0.520	0.013	0.020	
b1	0.400	0.580	0.016	0.023	
С	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.550 REF.		0.061 REF.		
E	2.300	2.600	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
е	1.500 TYP.		0.060 TYP.		
e1	3.000 TYP.		0.118 TYP.		
L	0.900	1.200	0.035	0.047	

# Suggested Pad Layout



- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

#### **REEL SPECIFICATION**

P/N	PKG	QTY
2SD882-MS	SOT-89	1000



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